

این دیتاشیت توسط توکل الکترونیک تهیه و ارائه شده است.
جهت مشاهده قیمت، موجودی و ثبت سفارش این قطعه به وبسایت توکل الکترونیک مراجعه فرمایید.

**مشاهده قیمت و خرید**

برای خرید و مشاهده سایر محصولات کلیک کنید



2SK1836, 2SK1837

Silicon N-Channel MOS FET

HITACHI

Application

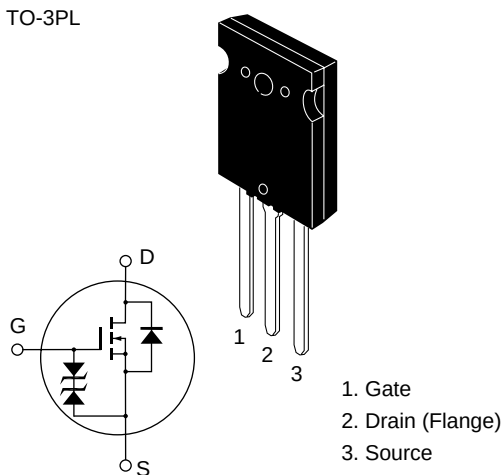
High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator, DC-DC converter

Outline

TO-3PL



2SK1836, 2SK1837

Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Ratings	Unit
Drain to source voltage	K1836	V _{DSS}	450	V
	K1837		500	
Gate to source voltage		V _{GSS}	±30	V
Drain current		I _D	50	A
Drain peak current		I _{D(pulse)} ^{*1}	200	A
Body to drain diode reverse drain current		I _{DR}	50	A
Channel dissipation		Pch ^{*2}	250	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	−55 to +150	°C

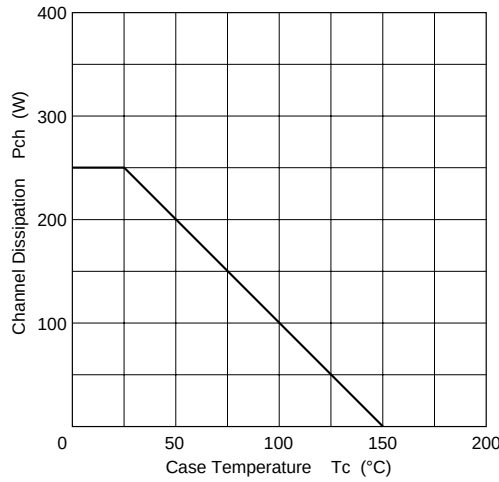
Notes 1. PW ≤ 10 μs, duty cycle ≤ 1 %
 2. Value at Tc = 25 °C

Electrical Characteristics (Ta = 25°C)

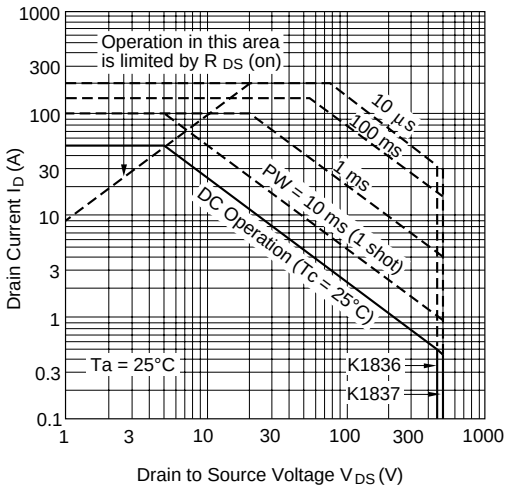
Item		Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	K1836 K1837	$V_{(BR)DSS}$	450 500	— —	— —	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage		$V_{(BR)GSS}$	±30	—	—	V	$I_G = \pm 100 \mu\text{A}$, $V_{DS} = 0$
Gate to source leak current		I_{GSS}	—	—	±10	μA	$V_{GS} = \pm 25 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	K1836 K1837	I_{DSS}	— —	— —	250	μA	$V_{DS} = 360 \text{ V}$, $V_{GS} = 0$ $V_{DS} = 400 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage		$V_{GS(off)}$	2.0	—	3.0	V	$I_D = 1 \text{ mA}$, $V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	K1836 K1837	$R_{DS(on)}$	— —	0.08 0.085	0.10 0.11	Ω	$I_D = 25 \text{ A}$ $V_{GS} = 10 \text{ V}^{*1}$
Forward transfer admittance		$ y_{fs} $	22	35	—	S	$I_D = 25 \text{ A}$ $V_{DS} = 10 \text{ V}^{*1}$
Input capacitance		C_{iss}	—	8150	—	pF	$V_{DS} = 10 \text{ V}$
Output capacitance		C_{oss}	—	2100	—	pF	$V_{GS} = 0$
Reverse transfer capacitance		C_{rss}	—	180	—	pF	$f = 1 \text{ MHz}$
Turn-on delay time		$t_{d(on)}$	—	80	—	ns	$I_D = 25 \text{ A}$
Rise time		t_r	—	250	—	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time		$t_{d(off)}$	—	550	—	ns	$R_L = 1.2 \Omega$
Fall time		t_f	—	220	—	ns	
Body to drain diode forward voltage		V_{DF}	—	1.1	—	V	$I_F = 50 \text{ A}$, $V_{GS} = 0$
Body to drain diode reverse recovery time		t_{rr}	—	620	—	ns	$I_F = 50 \text{ A}$, $V_{GS} = 0$, $di_F / dt = 100 \text{ A} / \mu\text{s}$

Note 1. Pulse Test

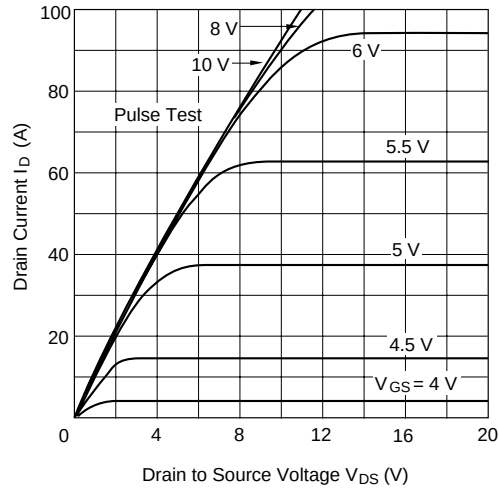
Power vs. Temperature



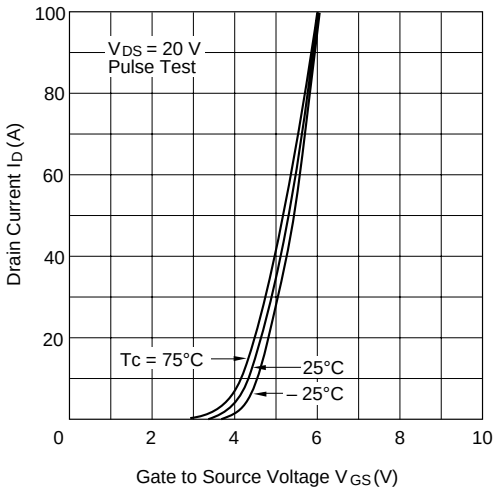
Maximum Safe Operation Area



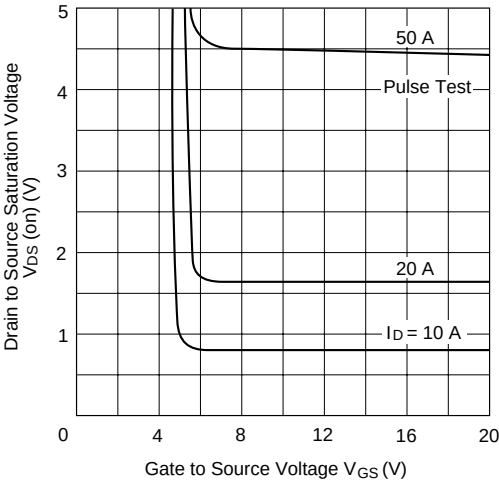
Typical Output Characteristics



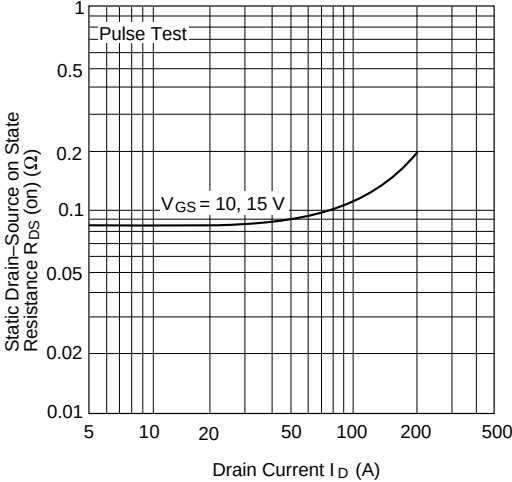
Typical Transfer Characteristics



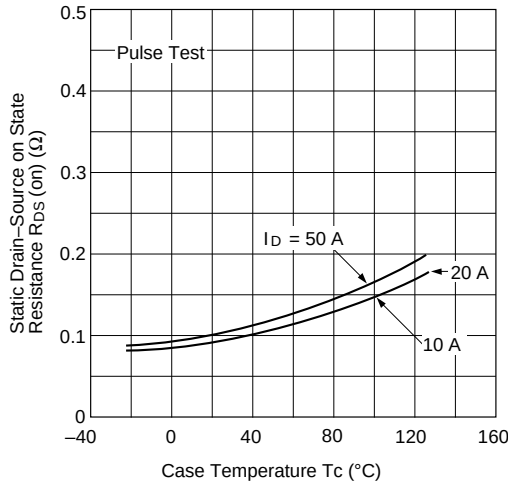
Drain to Source Saturation Voltage
vs. Gate to Source Voltage



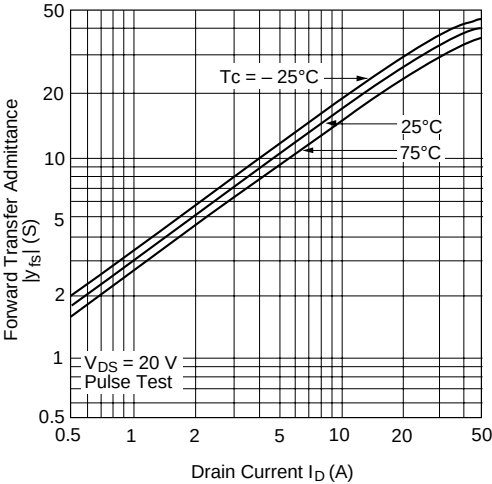
Static Drain to Source on State
Resistance vs. Drain Current



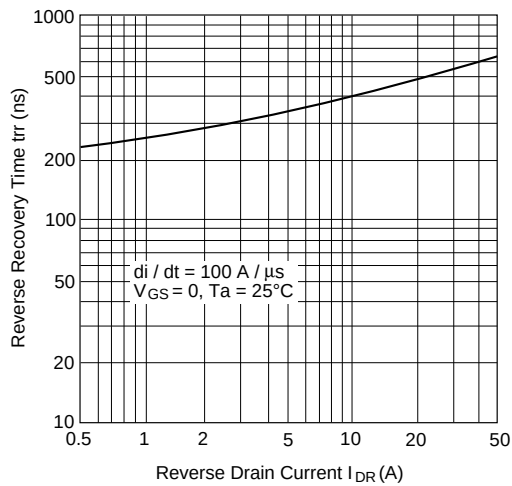
Static Drain to Source on State
Resistance vs. Temperature



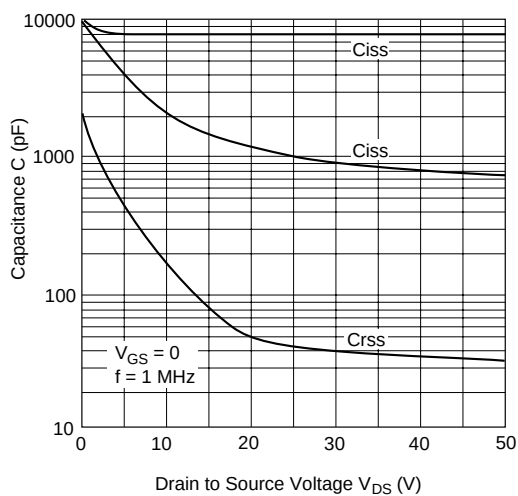
Forward Transfer Admittance
vs. Drain Current



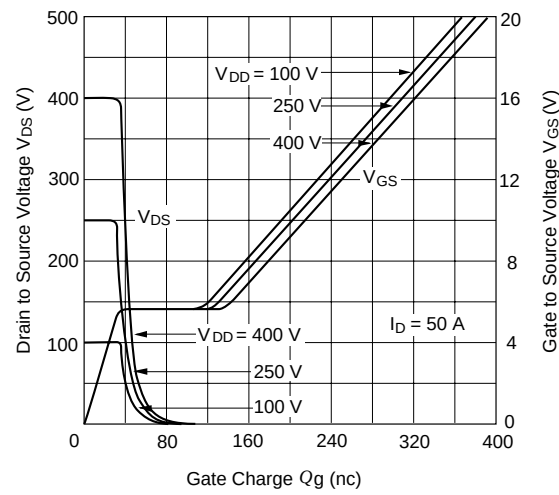
Body to Drain Diode Reverse
Recovery Time



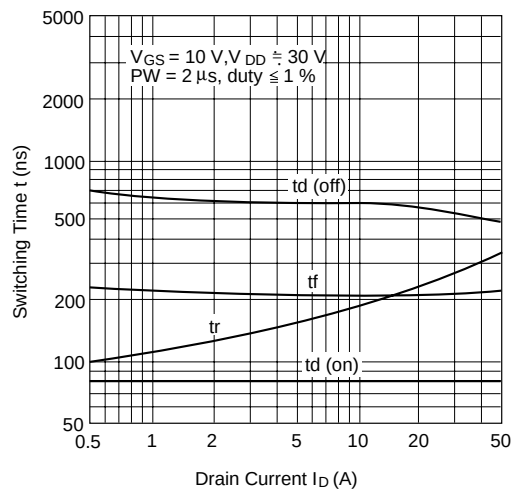
Typical Capacitance
vs. Drain to Source Voltage

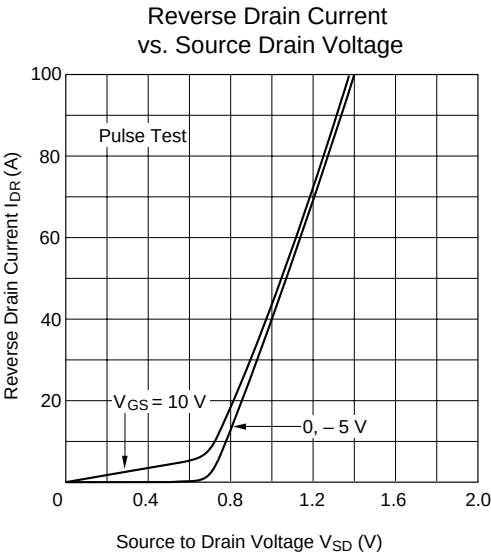
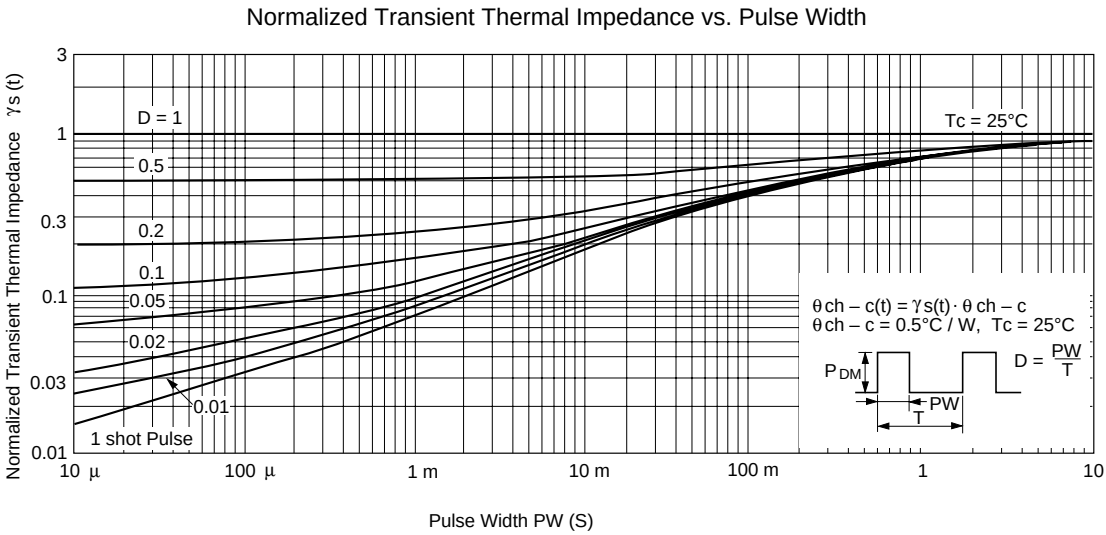


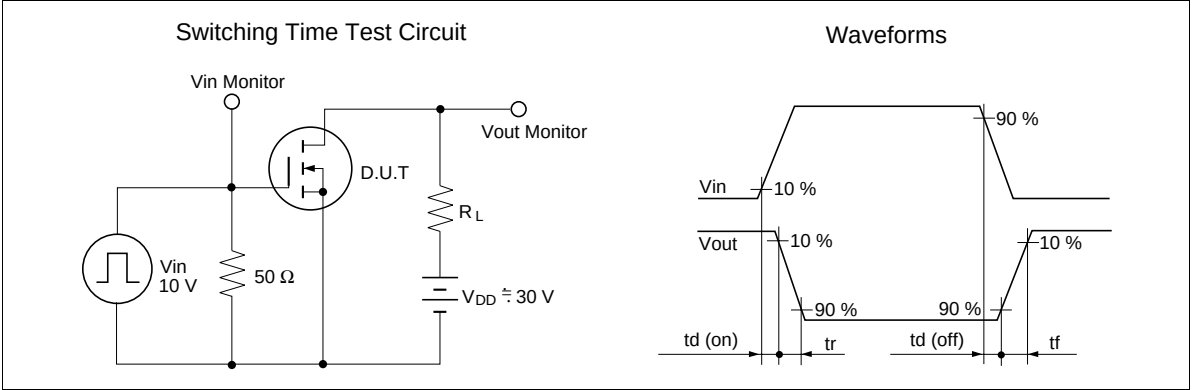
Dynamic Input Characteristics



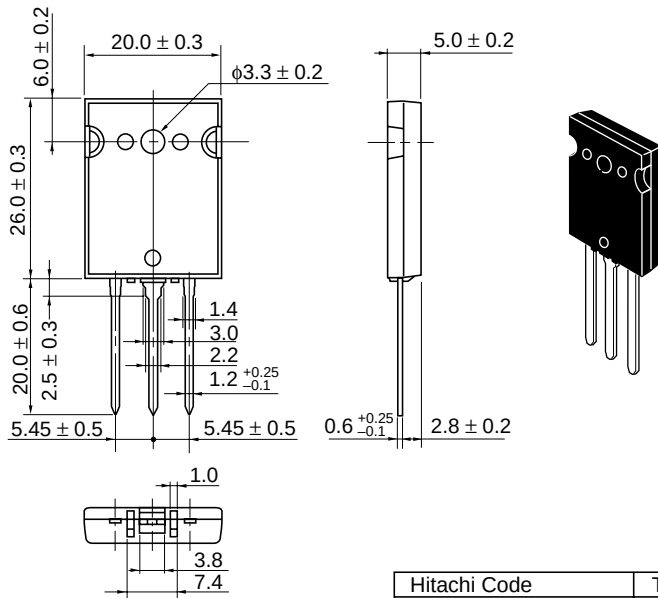
Switching Characteristics







Unit: mm



Hitachi Code	TO-3PL
JEDEC	—
EIAJ	—
Weight (reference value)	9.9 g

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